

**LOW POWER LOW OFFSET VOLTAGE DUAL COMPARATORS AS393/393A****General Description**

The AS393/393A consist of two independent precision voltage comparators with a typical offset voltage of 1.0mV and high gain. They are specifically designed to operate from a single power supply over wide range of voltages. Operation from split power supply is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

The AS393/393A series are compatible with industry standard 393. AS393A has more stringent input offset voltage than AS393.

The AS393 is available in standard DIP-8, SOIC-8 TSSOP-8 packages, AS393A is available in standard DIP-8 and SOIC-8 packages.

Features

- Wide Supply Voltage Range
 - Single Supply: 2.0V to 36V
 - Dual Supplies: $\pm 1.0V$ to $\pm 18V$
- Low Supply Current Drain: 0.6mA
- Low Input Bias Current: 25nA (Typical)
- Low Input Offset Current: $\pm 5.0nA$ (Typical)
- Low Input Offset Voltage: 1.0mV (Typical)
- Input Common Mode Voltage Range Includes Ground
- Differential Input Voltage Range Equals to the Power Supply Voltage
- Low Output Saturation Voltage: 200mV at 4mA
- Open Collector Output

Applications

- Battery Charger
- Cordless Telephone
- Switching Power Supply
- DC-DC Module
- PC Motherboard
- Communication Equipment

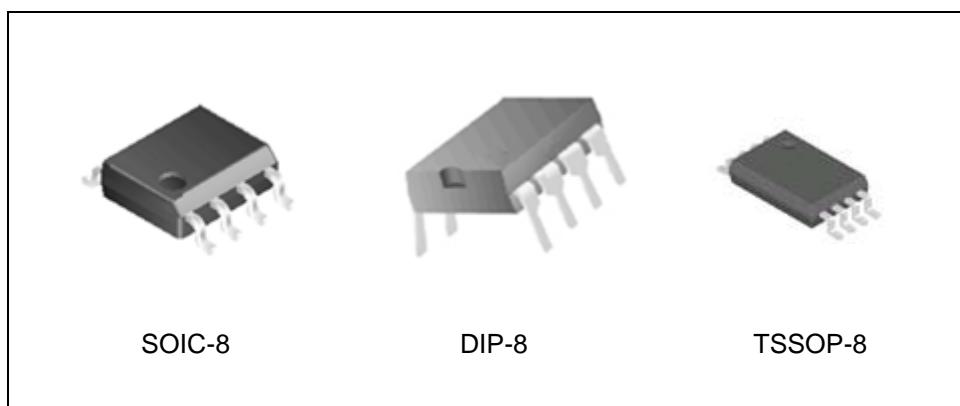


Figure 1. Package Types of AS393/393A



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Pin Configuration

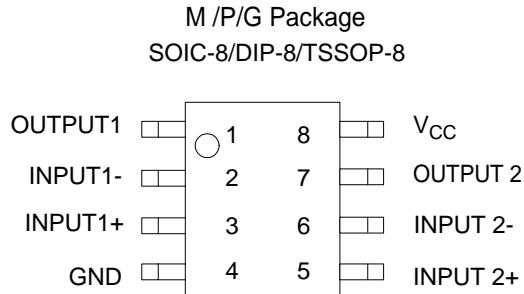


Figure 2. Pin Configuration of AS393/393A (Top View)

Functional Block Diagram

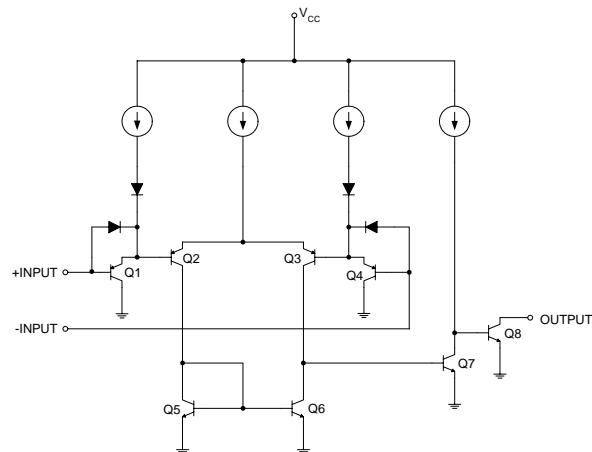
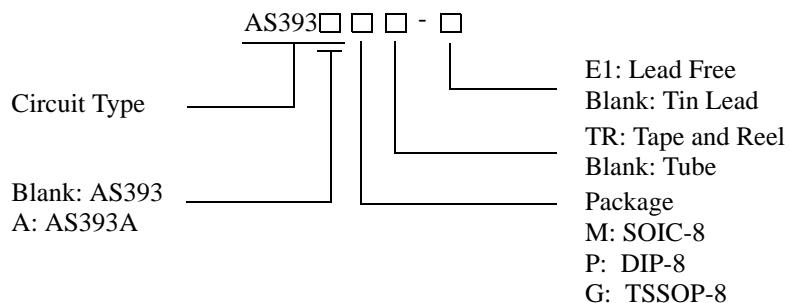


Figure 3. Functional Block Diagram of AS393/393A (Each comparator)

Ordering Information



**LOW POWER LOW OFFSET VOLTAGE DUAL COMPARATORS AS393/393A****Ordering Information (Continued)**

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Tin Lead	Lead Free	Tin Lead	Lead Free	
SOIC-8	-40 to 85°C	AS393M	AS393M-E1	AS393M	AS393M-E1	Tube
		AS393MTR	AS393MTR-E1	AS393M	AS393M-E1	Tape & Reel
			AS393AM-E1		AS393AM-E1	Tube
			AS393AMTR-E1		AS393AM-E1	Tape & Reel
DIP-8		AS393P	AS393P-E1	AS393P	AS393P-E1	Tube
			AS393AP-E1		AS393AP-E1	Tube
TSSOP-8			AS393G-E1		EG3C	Tube
			AS393GTR-E1		EG3C	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Supply Voltage	V _{CC}	40		V
Differential Input Voltage	V _{ID}	40		V
Input Voltage	V _{IN}	-0.3 to 40		V
Input Current (V _{IN} < -0.3V) (Note 2)	I _{IN}	50		mA
Output Short-Circuit Current to Ground		Continuous		
Power Dissipation (T _A =25°C)	P _D	DIP-8	780	mW
		SOIC-8	660	
		TSSOP-8	570	
Operating Junction Temperature	T _J	150		°C
Storage Temperature	T _{STG}	-65 to 150		°C
Lead Temperature (Soldering, 10 sec)	T _{LEAD}	260		°C

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V₊ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 V_{DC} (at 25°C).



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Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	2	36	V
Operating Temperature Range	T _A	-40	85	°C

Electrical Characteristics

Limits in standard typeface are for T_A=25°C, **bold** typeface applies over T_A=-40°C to 85°C (Note 3), V_{CC}=5V, GND=0V, unless otherwise specified.

Parameter	Conditions	Min	Typ	Max	Unit
Input Offset Voltage	V _O =1.4V, R _S =0Ω, V _{CC} =5V to 30V	AS393	1.0	5.0	mV
				7	
	V _{CM} =0V	AS393A	1.0	3.0	
				5	
Input Bias Current	I _{IN+} or I _{IN-} with output in Linear Range, V _{CM} =0V		25	250	nA
				400	
Input Offset Current	I _{IN+} -I _{IN-} , V _{CM} =0V		5.0	50	nA
				200	
Input Common Mode Voltage Range (Note 4)	V _{CC} =30V	0		V _{CC} -1.5	V
Supply Current	R _L =∞	V _{CC} =5V	0.6	1.0	mA
				2	
	V _{CC} =30V		0.7	1.7	
				3	
Voltage Gain	V _{CC} =15V, R _L ≥15kΩ, V _O =1V to 11V	50	200		V/mV
Large Signal Response Time	V _{IN} =TTL Logic Swing, V _{REF} =1.4V, V _{RL} =5V, R _L =5.1k		200		ns
Response Time	V _{RL} =5V, R _L =5.1K		1.3		μs
Output Sink Current	V _{IN} =1V, V _{IN} +0, V _O =1.5V	6.0	16		mA
Output LeackageCurrent	V _{IN} =0V, V _{IN} +1V, V _O =5V		0.1		nA
	V _{IN} =0V, V _{IN} +1V, V _O =30V			1	μA
Saturation Voltage	V _{IN} =1V, V _{IN} +0, I _{SINK} ≤4mA	200	400		mV
				500	

Note 3: These specifications are limited to -40°C ≤ T_A ≤ 85°C. Limits over temperature are guaranteed by design, but not tested in production.

Note 4: The input common-mode voltage of either input signal voltage should not be allowed to go negatively by more than 0.3V (at 25°C). The upper end of the common-mode voltage range is V_{CC}-1.5V (at 25°C), but either or both inputs can go to +18V without damages, independent of the magnitude of the V_{CC}.



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Typical Performance Characteristics

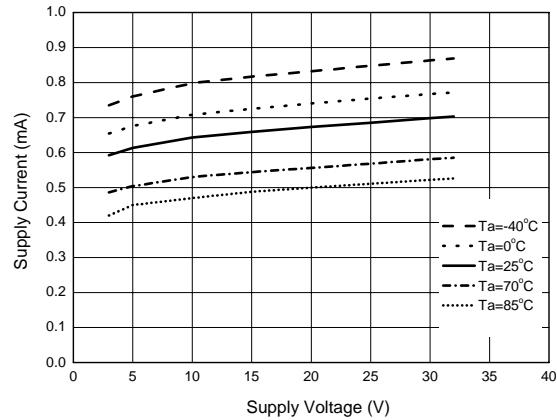


Figure 4. Supply Voltage vs. Supply Current

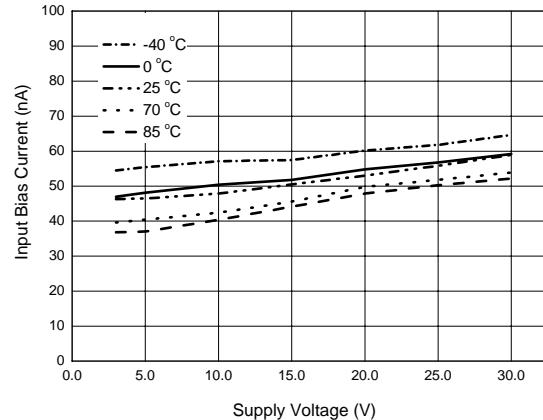


Figure 5. Supply Voltage vs. Input Bias Current

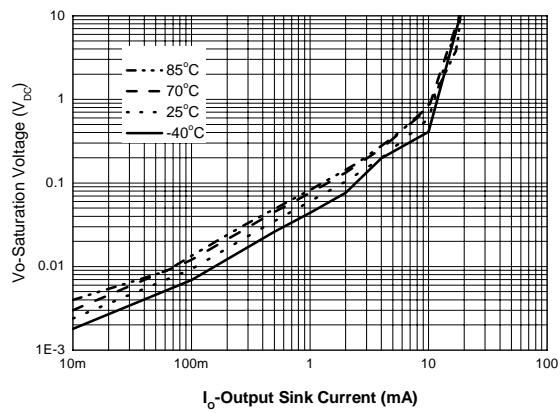


Figure 6. Output Sink Current vs. Saturation Voltage

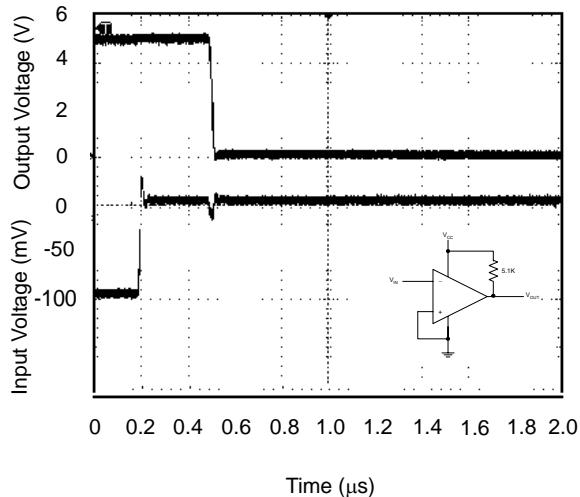


Figure 7. Response Time for 5mV Input Overdrive - Negative Transition



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Typical Performance Characteristics (Continued)

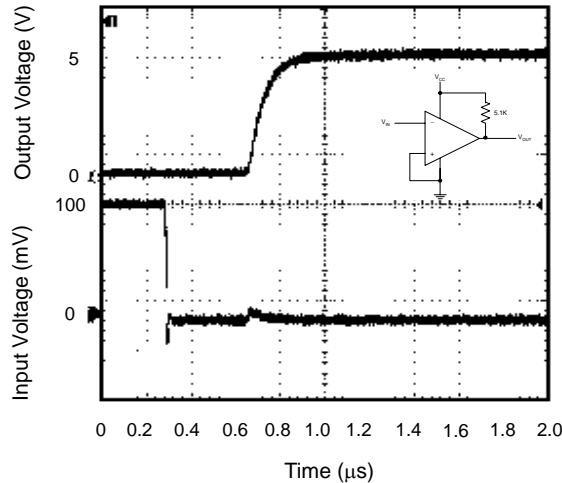


Figure 8. Response Time for 5mV Input Overdrive -
Positive Transition

Typical Applications

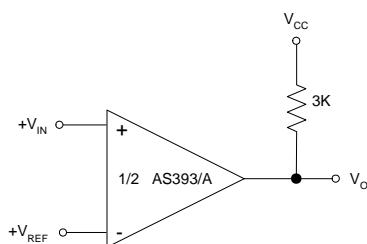


Figure 9. Basic Comparator

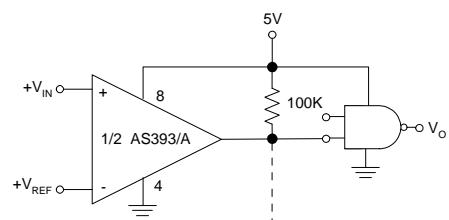


Figure 10. Driving CMOS



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Typical Applications (Continued)

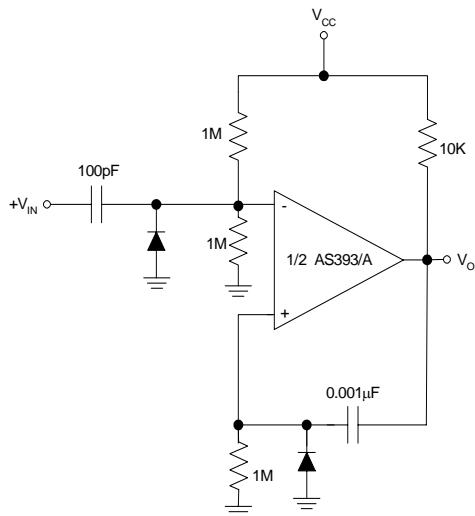


Figure 11. One Shot Multivibrator

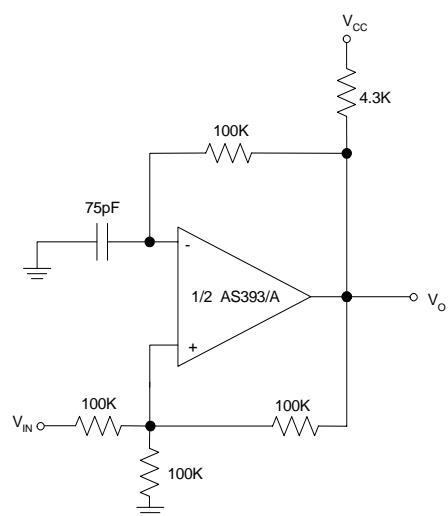


Figure 12. Squarewave Oscillator



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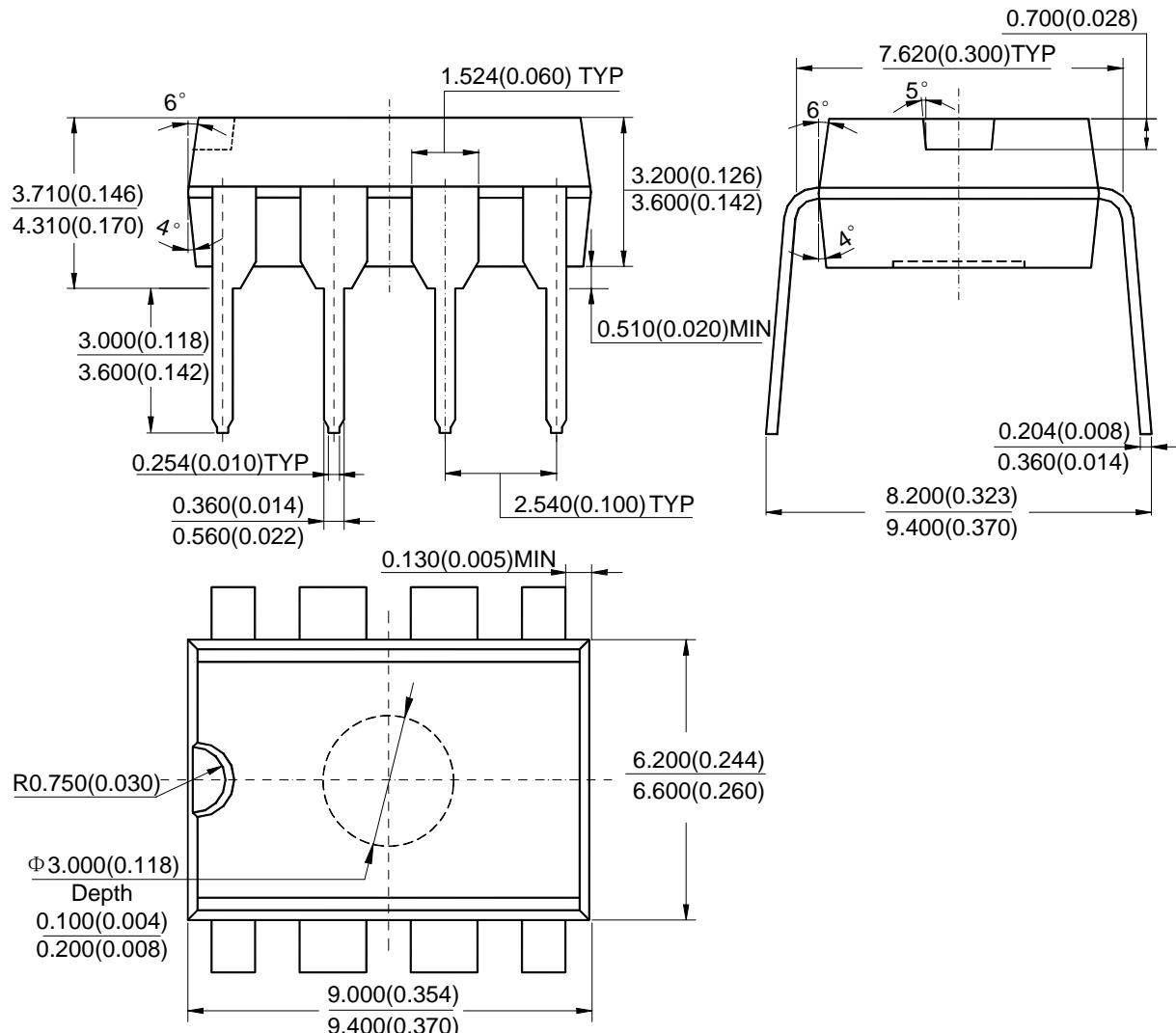
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LOW POWER LOW OFFSET VOLTAGE DUAL COMPARATORS AS393/393A

Mechanical Dimensions

DIP-8

Unit: mm(inch)





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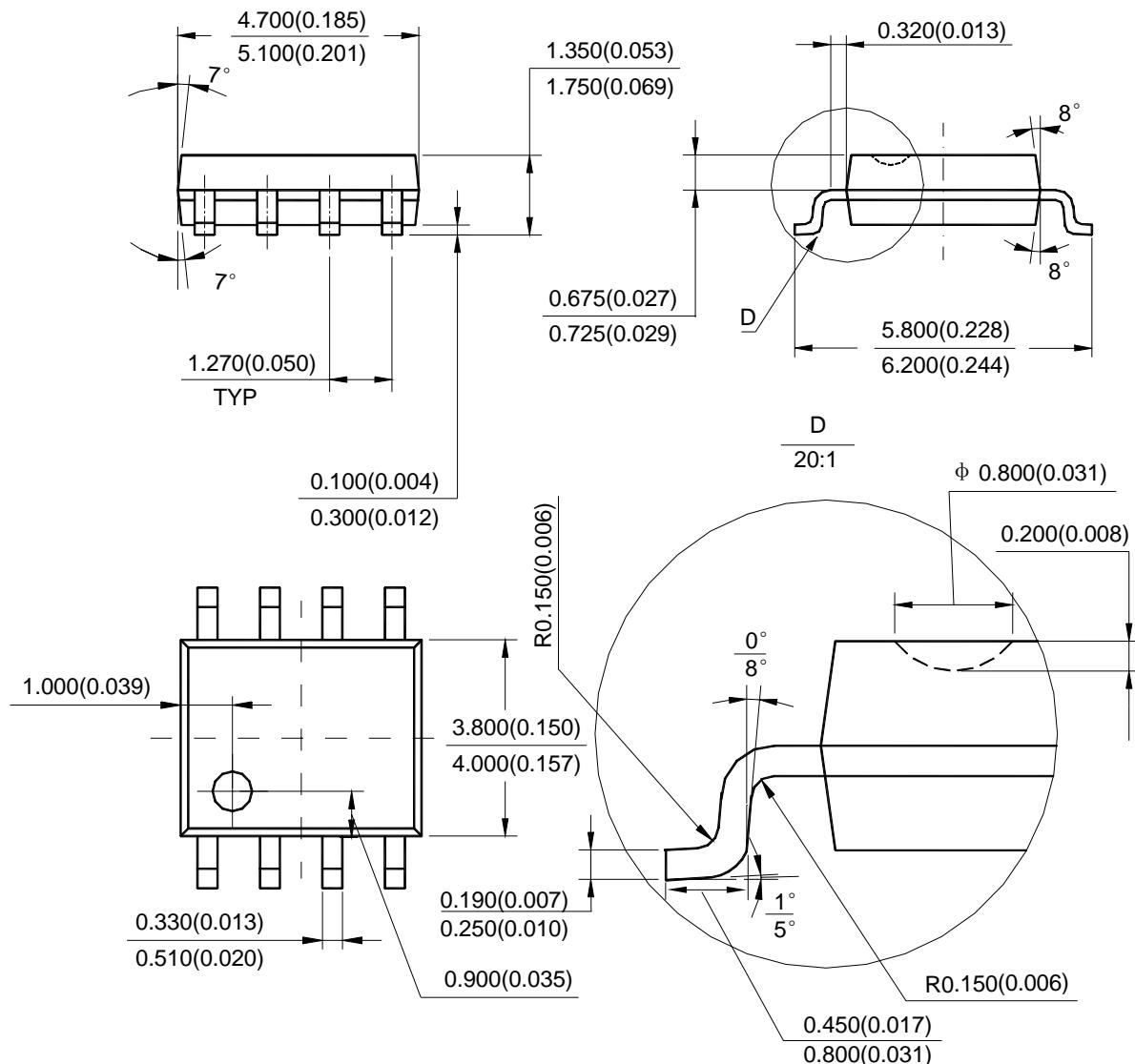
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LOW POWER LOW OFFSET VOLTAGE DUAL COMPARATORS AS393/393A

Mechanical Dimensions (Continued)

SOIC-8

Unit: mm(inch)





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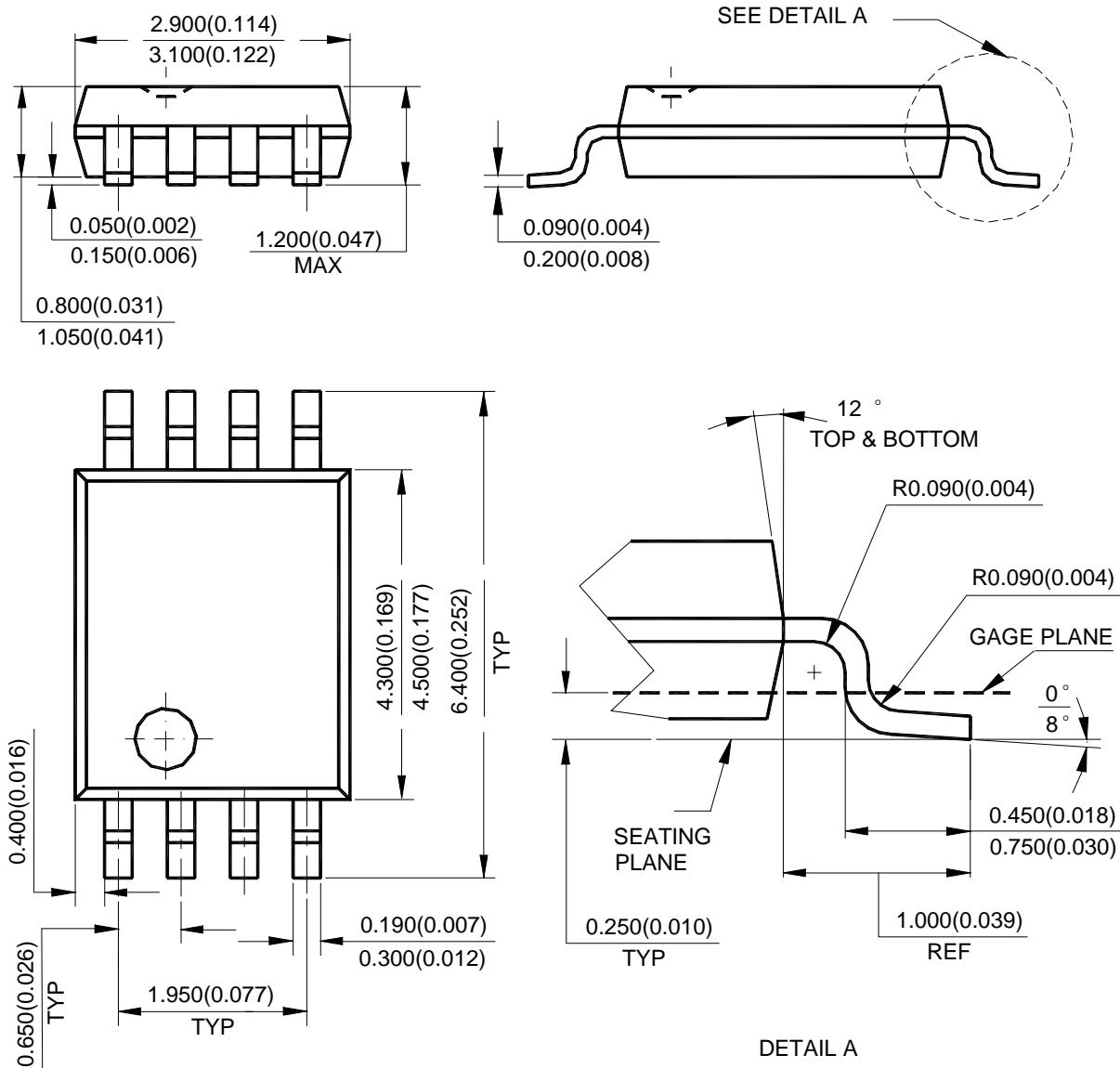
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LOW POWER LOW OFFSET VOLTAGE DUAL COMPARATORS AS393/393A

Mechanical Dimensions (Continued)

TSSOP-8

Unit: mm(inch)





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